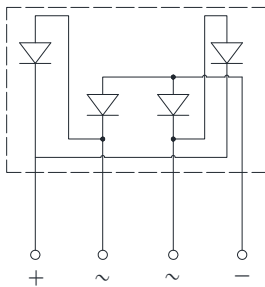
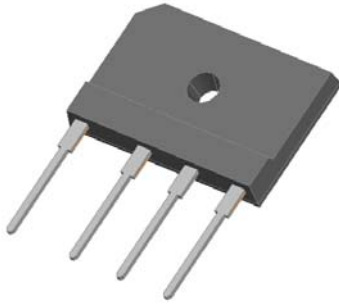


Low VF Bridge Rectifiers



Features

- UL recognition, file #E230084
- based on silicon planar process
- Low VF
- Thin single in-line package
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, industrial automation applications.

Mechanical Data

- **Package:** 6KBJ
Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	GBJU2506	
Device marking code			GBJU2506	
Maximum Repetitive Peak Reverse Voltage	VRRM	V	600	
Maximum RMS Voltage	VRMS	V	420	
Maximum DC blocking Voltage	VDC	V	600	
Average rectified output current @60Hz sine wave, R-load	With heatsink T _c =115°C	I _O	A	25.0
	Without heatsink T _a =25°C			4.5
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave, 1 cycle, T _j =25°C	IFSM	A	360	
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, T _j =25°C			720	
Current squared time @1ms≤t≤8.3ms T _j =25°C, Rating of per diode	I ² t	A ² S	538	
Storage temperature	T _{stg}	°C	-55 ~ +150	
Junction temperature	T _j	°C	-55 ~ +150	
Dielectric strength @ Terminals to case, AC 1 minute	V _{dis}	KV	2.5	
Mounting torque @Recommend torque: 5kg·cm	Tor	kg·cm	8	

■ **Electrical Characteristics** (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V _F	V	IFM=12.5A	0.80	0.875	0.92
DC reverse current at rated DC blocking voltage per diode	I _R	μA	T _j =25°C	-	0.001	5
			T _j =125°C	-	-	50
Junction capacitance	C _j	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	150	185	250

■ **Thermal Characteristics** (T_a=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	GBJU2506
Typical Thermal Resistance	Between junction and ambient, Without heatsink	R _{θJ-A}	°C/W	18.0
	Between junction and case, With heatsink	R _{θJ-C}		0.8
	Between junction and Lead With heatsink	R _{θJ-L}		5.0

Note: Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

■ **Ordering Information (Example)**

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
GBJU2506	B1	Approximate 6.5	15	750	1500	TUBE

■ **Characteristics(Typical)**

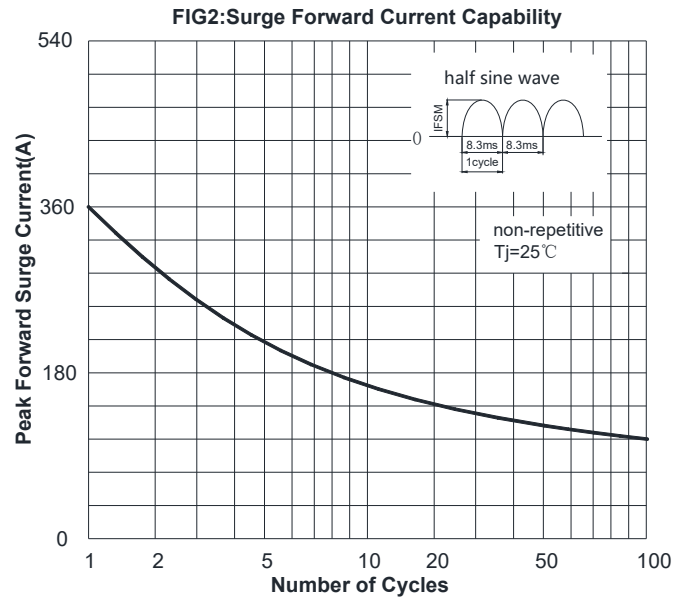
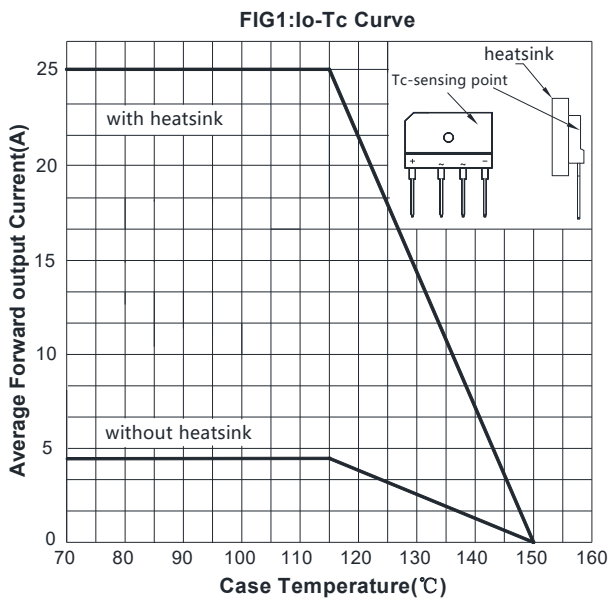


FIG3: Typical Forward Voltage

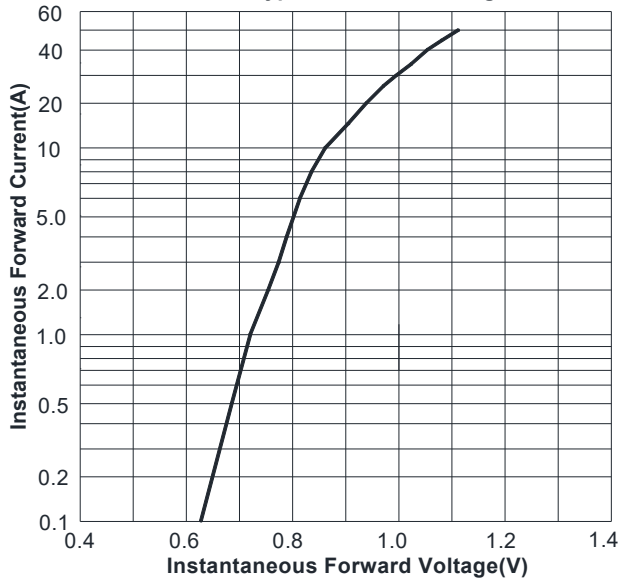
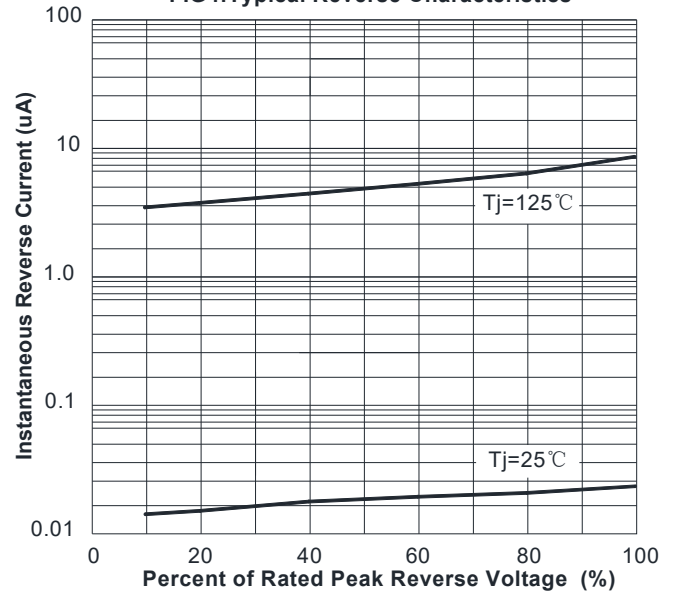
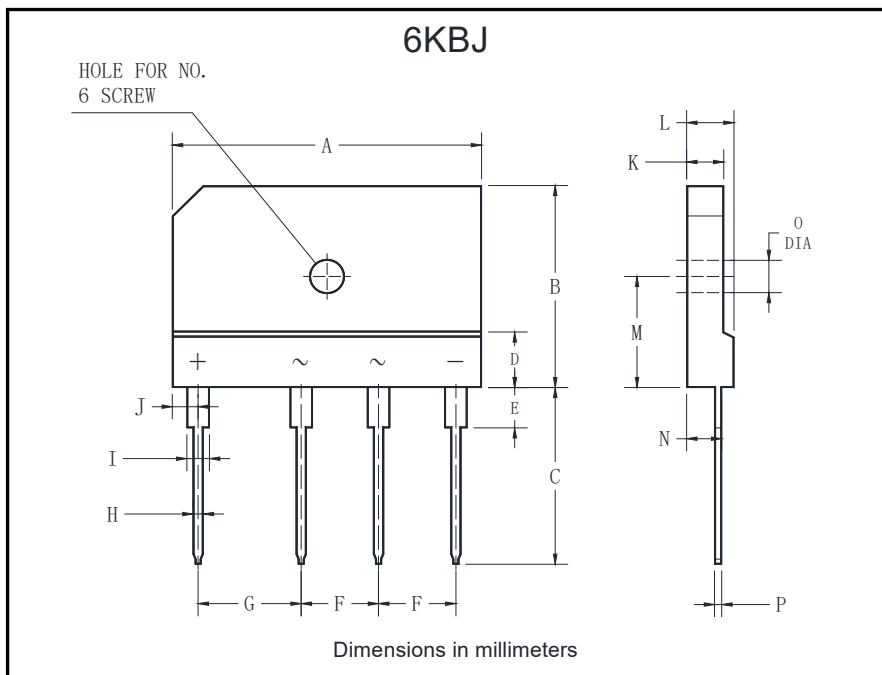


FIG4: Typical Reverse Characteristics



■ Outline Dimensions



6KBJ		
Dim	Min	Max
A	29.7	30.3
B	19.7	20.3
C	17.0	18.0
D	4.8	5.8
E	3.8	4.2
F	7.3	7.7
G	9.8	10.2
H	0.9	1.1
I	2.0	2.4
J	2.3	2.7
K	3.4	3.8
L	4.4	4.8
M	10.8	11.2
N	3.1	3.7
O	3.1	3.4
P	0.6	0.8

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